

of Structural Chemistry and Fujian Province Natural Science Foundation.

Lists of structure factors, anisotropic displacement parameters and complete geometry have been deposited with the IUCr (Reference: BR1112). Copies may be obtained through The Managing Editor, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

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Acta Cryst. (1996). **C52**, 2127–2129

The Binary Hafnium Phosphide Hf₃P₂

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(Received 28 February 1996; accepted 16 April 1996)

Abstract

The structure of trihafnium diphosphide, Hf₃P₂, has been redetermined by single-crystal analysis. Hf₃P₂ crystallizes in the orthorhombic space group *Pnma* (No. 62), with $a = 10.128(2)$, $b = 3.5707(6)$, $c = 9.868(2)$ Å, $V = 356.87(12)$ Å³, and the *anti*-Sb₂S₃ structure type. The P atoms are situated in singly capped and bicapped trigonal Hf prisms. In contrast to the structure of Zr₁₄P₉, no centered Hf cubes as observed in the bcc packing occur in the structure of Hf₃P₂.

Comment

Significant differences in composition and crystal structure occur in the binary Zr–P and Hf–P systems. The Hf analogues of α -ZrP (Schönberg, 1954), Zr₇P₄ (Ahlzén & Rundqvist, 1989) and Zr₁₄P₉ (Tergenius, Nöläng &

Lundström, 1981) were unknown until recently we were able to synthesize Hf₇P₄ (Kleinke & Franzen, 1996a). In order to confirm earlier reports of Hf₃P₂ (Lundström, 1968), which has no Zr counterpart, we reinvestigated its crystal structure. We determined the structure with higher precision than in 1968, using a four-circle diffractometer with a rotating anode.

Hf₃P₂ crystallizes in the *anti*-Sb₂S₃ structure type, consisting of singly capped and bicapped trigonal Hf₆P prisms. Whereas the Zr sublattice of Zr₁₄P₉ (Zr:P ratio = 3.11:2) can be described in terms of bcc packing, these structure motifs are not found in Hf₃P₂. The three crystallographically different Hf atoms have high coordination numbers, ranging from 14 to 16. Each Hf atom is surrounded by five P atoms at distances between 2.599(4) and 3.077(4) Å, and from nine to eleven Hf neighbors at distances between 3.052(1) and 3.674(1) Å.

No regular coordination polyhedra were found around the Hf atoms. Therefore, the structure is best described by the three-dimensional connection of Hf₆P prisms, *i.e.* the Hf₆P1 prisms are interconnected *via* opposite triangular faces forming chains running parallel to [010], and the Hf₆P2 prisms, lying perpendicular to the Hf₆P1 prisms, form infinite chains parallel to [010] and share common edges (Fig. 1). Two chains of the Hf₆P2 prisms form a double chain sharing one common edge. The two crystallographically different Hf₆P prisms are interconnected *via* a rectangular face in one direction and *via* one common edge in a second direction,

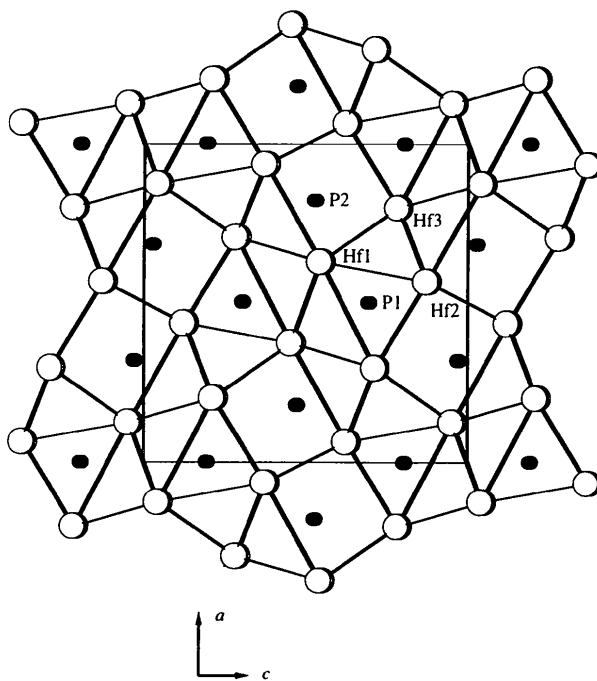


Fig. 1. Projection of the structure of Hf₃P₂ along [010]. Small filled circles represent P atoms and large open circles represent Hf atoms.

resulting in a three-dimensional structure. From another point of view, the Hf atoms form a three-dimensional network with the P atoms in trigonal prismatic voids. Altogether, the structural differences between Zr and Hf phosphides are confirmed for the *M*:P ratio of *ca.* 3:2. Although it is generally understood that the 5*d* metals tend to form structures with a higher metal–metal bond order (Franzen & Köckerling, 1995), this generalization cannot totally explain the different behavior of Zr and Hf, which is observed in case of the phosphides with the approximate ratio of 3:2, but not for the ratio 7:4. Further investigations of the similarities and differences are currently in progress.

Experimental

HfP was synthesized in an evacuated fused silica tube at a reaction temperature of 1073 K, starting from the elements in the stoichiometric ratio [Hf: Alfa Products, powder, –325 mesh (<0.044 mm), purity 99.6% (2–3.5% Zr); P: Alfa, powder, –100 mesh (<0.149 mm), red amorphous, 99%]. Co was obtained from Alfa [powder, –50 + 150 mesh (0.100–0.297 mm), 99.9%]. Needle-like single crystals of Hf₃P₂ were obtained after arc-melting of HfP, Hf and Co in the ratio 3:2:1 and subsequent annealing in an induction furnace at 1673 K over a period of 6 h. The powder diagram, obtained from the ground bulk sample, contained only the reflections of Hf₃P₂ and Hf₅Co_{1+x}P_{3-x} (Kleinke & Franzen, 1996b).

Crystal data

Hf₃P₂
M_r = 597.41
 Orthorhombic
Pnma
a = 10.128 (2) Å
b = 3.5707 (6) Å
c = 9.868 (2) Å
V = 356.87 (12) Å³
Z = 4
D_x = 11.119 Mg m⁻³

Mo Kα radiation
 λ = 0.71069 Å
 Cell parameters from 18 reflections
 θ = 6.4–23.41°
 μ = 87.674 mm⁻¹
T = 293 (2) K
 Needle-like
 0.1 × 0.01 × 0.01 mm
 Black

Data collection

Rigaku AFC-6R diffractometer
 2θ/ω scans
 Absorption correction: ψ scan (TEXSAN; Molecular Structure Corporation, 1989)
T_{min} = 0.44, *T_{max}* = 0.99
 1457 measured reflections
 548 independent reflections

443 observed reflections
 $[I > 2\sigma(I)]$
 $R_{int} = 0.077$
 $\theta_{max} = 30.06^\circ$
 $h = 0 \rightarrow 12$
 $k = -3 \rightarrow 5$
 $l = -13 \rightarrow 13$
 3 standard reflections monitored every 150 reflections
 intensity decay: none

Refinement

Refinement on *F*²
 $R[F^2 > 2\sigma(F^2)] = 0.0293$
 $wR(F^2) = 0.0574$
S = 1.085
 548 reflections

Extinction correction: SHELXL93 (Sheldrick, 1993)
 Extinction coefficient: 0.00014 (11)

32 parameters

$$w = 1/[\sigma^2(F_o^2) + 1.3185P]$$

$$\text{where } P = (F_o^2 + 2F_c^2)/3$$

$$(\Delta/\sigma)_{max} < 0.001$$

$$\Delta\rho_{max} = 3.38 \text{ e } \text{Å}^{-3}$$

$$\Delta\rho_{min} = -3.19 \text{ e } \text{Å}^{-3}$$

Atomic scattering factors from *International Tables for Crystallography* (1992, Vol. C, Tables 4.2.6.8 and 6.1.1.4)

Table 1. Fractional atomic coordinates and equivalent isotropic displacement parameters (Å²)

$$U_{eq} = (1/3)\sum_i\sum_j U_{ij}a_i^*a_j^*a_i \cdot a_j$$

	<i>x</i>	<i>y</i>	<i>z</i>	<i>U_{eq}</i>
Hf1	0.04686 (6)	1/4	0.12605 (6)	0.0032 (2)
Hf2	0.37636 (7)	1/4	0.06432 (5)	0.0033 (2)
Hf3	0.21585 (7)	1/4	0.79665 (6)	0.0038 (2)
P1	0.3066 (4)	1/4	0.4991 (4)	0.0059 (8)
P2	0.4729 (4)	1/4	0.8203 (4)	0.0039 (9)

Table 2. Selected geometric parameters (Å)

Hf1—P2 ⁱⁱ	2.627 (3)	Hf2—Hf3 ^{viii}	3.1016 (10)
Hf1—P1 ⁱⁱ	2.638 (3)	Hf2—Hf2 ^{xi, xii}	3.3274 (12)
Hf1—P1 ⁱⁱⁱ	2.729 (4)	Hf2—Hf1 ^{xiii}	3.5097 (10)
Hf1—Hf1 ^{ix, v}	3.2057 (11)	Hf3—P2	2.614 (4)
Hf1—Hf3 ^{vi, vii}	3.2938 (9)	Hf3—P1 ^{xiv, xv}	2.689 (3)
Hf1—Hf2	3.3923 (12)	Hf3—P2 ^{xvi}	2.718 (4)
Hf1—Hf3 ^{ii, ii}	3.4347 (8)	Hf3—Hf2 ^{xv, xv}	3.0521 (8)
Hf2—P2 ^{vii, viii}	2.599 (4)	Hf3—P1	3.077 (4)
Hf2—P2 ^{ix, x}	2.611 (3)	Hf3—Hf2 ^{xvii}	3.1016 (10)
Hf2—P1 ^{ii, ii}	2.652 (3)	Hf3—Hf1 ^{xviii, xviii}	3.2938 (9)
Hf2—Hf3 ⁱⁱ	3.0521 (8)	Hf3—Hf1 ^{xiv, xv}	3.4347 (8)

Symmetry codes: (i) $\frac{1}{2} - x, \frac{1}{2} + y, z - \frac{1}{2}$; (ii) $\frac{1}{2} - x, y - \frac{1}{2}, z - \frac{1}{2}$; (iii) $x - \frac{1}{2}, \frac{1}{2} - y, \frac{1}{2} - z$; (iv) $-x, -y, -z$; (v) $-x, 1 - y, -z$; (vi) $-x, -y, 1 - z$; (vii) $-x, 1 - y, 1 - z$; (viii) $x, y, z - 1$; (ix) $1 - x, 1 - y, 1 - z$; (x) $1 - x, -y, 1 - z$; (xi) $1 - x, 1 - y, -z$; (xii) $1 - x, -y, -z$; (xiii) $\frac{1}{2} + x, \frac{1}{2} - y, \frac{1}{2} - z$; (xiv) $\frac{1}{2} - x, \frac{1}{2} + y, \frac{1}{2} + z$; (xv) $\frac{1}{2} - x, y - \frac{1}{2}, \frac{1}{2} + z$; (xvi) $x - \frac{1}{2}, \frac{1}{2} - y, \frac{3}{2} - z$; (xvii) $x, y, 1 + z$; (xviii) $\frac{1}{2} + x, \frac{1}{2} - y, \frac{3}{2} - z$.

Data collection: *MSCIAFC Diffractometer Control Software* (Molecular Structure Corporation, 1993). Cell refinement: *MSCIAFC Diffractometer Control Software*. Data reduction: *TEXSAN* (Molecular Structure Corporation, 1989). Program(s) used to solve structure: *SHELXS86* (Sheldrick, 1985). Program(s) used to refine structure: *SHELXL93* (Sheldrick, 1993). Molecular graphics: *ATOMS* (Dowty, 1991). Software used to prepare material for publication: *SHELXL93*.

HK thanks the Deutsche Forschungsgesellschaft for financial support of this work. The Ames Laboratory is operated for the US Department of Energy by Iowa State University under contract No. W-7405-Eng-82. This research was also supported by the Office of the Basic Energy Sciences, Materials Science Division, Department of Energy.

Lists of structure factors, anisotropic displacement parameters and complete geometry have been deposited with the IUCr (Reference: BR1144). Copies may be obtained through The Managing Editor, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

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Acta Cryst. (1996). **C52**, 2129–2132

Tricaesium Ditellurium Tetravanadium Chloride Tetradecaoxide

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(Received 6 December 1995; accepted 5 March 1996)

Abstract

The title compound, $(\text{CsCl})\text{Cs}_2(\text{TeV}_2\text{O}_7)_2$, was obtained at 700 K during the crystallization of a mixed tellurium-caesium vanadate using tellurium tetrachloride as a transport agent. The structure consists of stacks of $[\text{V}_2\text{TeO}_7]$ sheets alternately separated by layers of caesium atoms and layers of caesium and chlorine atoms. Within the sheets, the V atoms are distributed over two sites: a tetrahedral site containing V^{5+} ions and a square pyramidal site containing V^{4+} ions. The Te^{4+} ion lies within a tetrahedron formed by three O atoms and a lone pair. A maximum in the electron density is observed at the expected position of the lone pair.

Comment

In our long-term research, we are particularly interested in mixed valence transition metal (M) oxides, among them the vanadium bronzes, $M'_x\text{V}_{2-x}^{5+}\text{V}_x^{4+}\text{O}_5$ ($M' = \text{Li}, \text{Na}, \text{K}, \text{Rb}, \text{Ag}$) (Galy, 1992; Savariault, Déramond & Galy, 1994; Déramond, Savariault & Galy, 1994; Hirschinger *et al.*, 1993; Savariault & Galy, 1992), and the so-called lone-pair elements, M^* , characterized by unusual stereochemical effects ($M^* = \text{As}^{3+}, \text{Se}^{4+}, \text{Sn}^{2+}, \text{Sb}^{3+}, \text{Te}^{4+}, \text{Pb}^{2+}, \text{Bi}^{3+}$) (Galy, Meunier, Andersson

& Åström, 1975; Enjalbert, Savariault & Galy, 1980; Galy & Enjalbert, 1982; Castro, Enjalbert, Schnuriger & Galy, 1990). These oxides also give a rich series of double oxides, among which are the compounds $M\text{V}^{5+}\text{Te}^{4+}\text{O}_5$, which are related to the vanadium bronzes in formula but are completely different in structure and physical properties (Darriet, Guillaume, Wilhelmi & Galy, 1972). Several phases containing M and M^* metals have been synthesized, particularly for $M = \text{V}$, for example $\text{Te}_2\text{V}_2\text{O}_9$ and α - and β - TeVO_4 (Darriet & Galy, 1973; Meunier, Darriet & Galy, 1972, 1973), but with vanadium simultaneously present in two different valence states. During studies of the crystal growth of CsVTeO_5 by chemical transport using TeCl_4 , the title compound was discovered.

A projection of the structure of the title compound onto the $[001]$ plane is given in Fig. 1, showing the presence of sheets of vanadium and tellurium oxide separated alternately by layers of caesium atoms and layers of caesium and chlorine atoms. The corresponding average distances between successive metal oxide layers are 5.68 and 6.12 Å, respectively. A view of a metal oxide sheet is given in Fig. 2. The V atoms lie in two types of site: atom V1 in a VO_5 square pyramid and atom V2 in a VO_4 tetrahedron. The Te^{4+} ion, bonded to three O atoms, has a lone pair (E), thus forming a TeO_3E tetrahedron. The VO_4 and TeO_3E tetrahedra share atom O4 [$\text{V2}-\text{O4}-\text{Te}$ 132.2(4)°] to form a pair of tetrahedra in a staggered conformation with an angle between the O-atom basal planes of 57.6(1)°. The O atoms of each base, O2 and O3, are shared with the basal plane of the V1O_5 pyramid. This leads to a sheet of formula

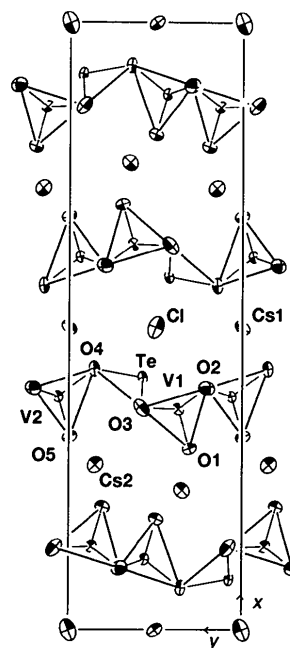


Fig. 1. A projection of the unit cell along the $[001]$ direction. Displacement ellipsoids are drawn at the 75% probability level.